Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-383-3846

| Inclosure Material: |
|----------------------------------------------------------------------|
| Metal and glass |
| Overall Length: |
| Between 0.130 inches and 0.150 inches |
| Overall Diameter: |
| Between 0.057 inches and 0.067 inches |
| Function For Which Designed: |
| Switching |
| Mounting Method: |
| Terminal |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 200.0 reverse voltage, instantaneous |
| Power Rating Per Characteristic: |
| 500.0 milliwatts small-signal input power, common-collector absolute |
| Maximum Operating Tempurature Per Measurement Point: |
| 150.0 degrees celsius ambient air |
| Terminal Type And Quantity: |
| 2 bonding pad |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |
| |
| |